TECHNICAL DATA DATA SHEET 519, REV. -

SILICON SCHOTTKY RECTIFIER DIE Very Low Forward Voltage Drop 200°C Operating Temperature

Applications:

• Switching Power Supply • Converters • Free-Wheeling Diodes • Polarity Protection Diode

Features:

- Soft Reverse Recovery at Low and High Temperature
- Very Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability
- Guaranteed Reverse Avalanche Characteristics
- Electrically / Mechanically Stable during and after Packaging
- Out Performs 100 Volt Ultrafast Rectifiers

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	100	V
Max. Average Forward	$I_{F(AV)}$	50% duty cycle, rectangular	7.5	Α
Current		wave form		
Max. Peak One Cycle Non-	I _{FSM}	8.3 ms, half Sine wave (1)	140	Α
Repetitive Surge Current				
Non-Repetitive Avalanche	E_AS	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 0.36 \text{A},$	5.4	mJ
Energy		L = 82 mH		
Repetitive Avalanche Current	I _{AR}	I _{AS} decay linearly to 0 in 1 μs	0.36	Α
		f limited by T _J max V _A =1.5V _R		
Max. Junction Temperature	T_J	-	-65 to +200	°C
Max. Storage Temperature	T_{stg}	-	-65 to +200	°C

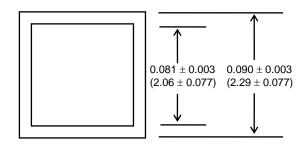
Electrical Characteristics:

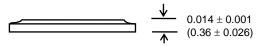
Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V_{F1}	@ 7.5A, Pulse, T _J = 25 °C	0.84	V
	V_{F2}	@ 7.5A, Pulse, T _J = 125 °C	0.68	V
Max. Reverse Current	I _{R1}	@V _R = 100V, Pulse,	180	μΑ
		T _J = 25 °C		
	I _{R2}	@V _R = 100V, Pulse,	4	mA
		T _J = 125 °C		
Max. Junction Capacitance	C _T	$@V_R = 5V, T_C = 25 ^{\circ}C$	250	pF
		$f_{SIG} = 1MHz,$		
		$V_{SIG} = 50 \text{mV (p-p)}$		

(1) in SHD package

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Mechanical Dimensions: In Inches / mm



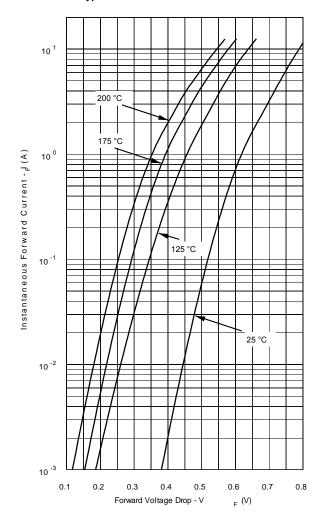


Bottom side metalization Ag - 30 kÅ minimum.

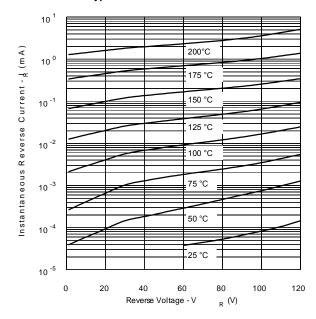
Top side metalization AI - 25 kÅ minimum or Ag - 30 kÅ minimum.

Bottom side is cathode, top side is anode.

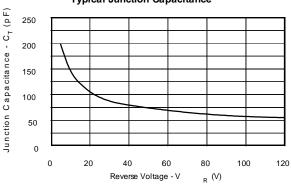
Typical Forward Characteristics



Typical Reverse Characteristics



Typical Junction Capacitance



SD090SC100A/B/C

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